NSN 5962-01-390-2013

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
End Application:
Vc-3993/sys-2 e/i fscm 21877
Features Provided:
Programmed and ultraviolet erasable and electrostatic sensitive
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Product Name:
32k x 8-bit prom
Voltage Rating And Type Per Characteristic:
4.5 volts applied and 5.5 volts applied
Time Rating Per Chacteristic:
70.00 nanoseconds access
Memory Device Type:
Prom
Hybrid Technology Type:
Monolithic
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883
standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
28 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
Yes - demil/mli
Filig:
A458a0